
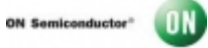


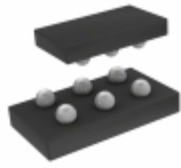
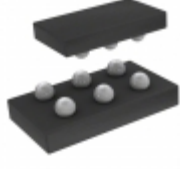
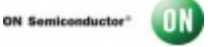

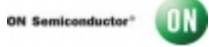
	<h2>EFC6601R-TR</h2>
	<p><b>Hersteller-Teilenummer:</b> EFC6601R-TR</p> <p><b>Hersteller / Marke:</b> AMI Semiconductor / ON Semiconductor</p> <p><b>Teil der Beschreibung:</b> MOSFET 2N-CH EFCP</p> <p><b>Datenblätter:</b>  <a href="#">EFC6601R-TR.pdf</a></p> <p><b>RoHs Status:</b> Bleifrei / RoHS-konform</p> <p><b>Lagerzustand:</b> New original, 42610 pcs Stock Available.</p> <p><b>Liefern von:</b> Hong Kong</p> <p><b>Versandweg:</b> DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

### Spezifikationen

Teilenummer	EFC6601R-TR
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	MOSFET 2N-CH EFCP
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	42610 pcs Stock
Serie	-
Betriebstemperatur	150 °C (TJ)
Befestigungsart	Surface Mount
Leistung - max	2W
Verpackung / Gehäuse	6-XFBGA
Supplier Device-Gehäuse	6-EFCP (2.7x1.81)
Typ FET	2 N-Channel (Dual)
FET-Merkmal	Logic Level Gate, 2.5V Drive
Drain-Source-Spannung (Vdss)	-
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	-
Rds On (Max) @ Id, Vgs	-
VGS (th) (Max) @ Id	-
Gate Charge (Qg) (Max) @ Vgs	48nC @ 4.5V
Eingabekapazität (Ciss) (Max) @ Vds	-
Verpackung	Tape & Reel (TR)



















































EFC6601R-TR ist neu im Original. Suche EFC6601R-TR Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie EFC6601R-TR AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage EFC6601R-TR: Info@Y-IC.com

Sie können auch interessiert sein:

 <p><b>EFC6604R-TF</b> AMI Semiconductor / ON Semiconductor EFC6604R-TF ON</p>	 <p><b>EFC4C002NLTGD</b> AMI Semiconductor / ON Semiconductor MOSFET 2 N-CHANNEL 8WLCSP</p>	 <p><b>EFC4630R-TR</b> AMI Semiconductor / ON Semiconductor INTEGRATED CIRCUIT</p>	 <p><b>EFC6602R-A-TR</b> AMI Semiconductor / ON Semiconductor MOSFET 2N-CH EFCP</p>
 <p><b>EFC6601R-A-TR</b> AMI Semiconductor / ON Semiconductor MOSFET 2N-CH EFCP</p>	 <p><b>EFC6604R-A-TR</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 24V 6A EFCP</p>	 <p><b>EFC4630R-TR</b> ON ON WLCSP4</p>	 <p><b>EFC4C012NLTGD</b> AMI Semiconductor / ON Semiconductor NCH 30V 30A WLCSP6 DUAL</p>

### heiße Teile

Mehr

 EFC2J001NUZ	 EFC2J003MUZTCG-E2	 EFC2J003NUZTCG	 EFC2J004NUZTDG	 EFC4601-M-TR
 EFC4601R-M-TR	 EFC4601R-TR	 EFC4602-S-TR	 EFC4611-TR	 EFC4612R-S-TR
 EFC4612R-TR	 EFC4615R-TR	 EFC4618R-P-TR	 EFC4618R-TR	 EFC4619R-TR
 EFC4621R-TR	 EFC4622R-W-N	 EFC4623R-TR	 EFC4624R	 EFC4626R-TR
 EFC4627R-A-TR	 EFC4630R-TR	 EFC4630R-TR	 EFC6602R-A-TR	 EFC6602R-TR
 EFC6604R-TF	 EFC6605R-TR	 EFC6605R-V-TR	 EFC6606R-TR	 EFC6607R
 EFC6611-A-TF	 EFC6611R-A-TF	 EFC6611R-A-TF	 EFC6611R-TF	 EFC6612R-A
 EFC6612R-TF	 EFC6617R-A-TF	 EFC6617R-TF	 EFC6617R-TF-ENG14	 EFC6618R-A
 EFC6618R-TF	 EFC8811R-TF	 EFC8822R-TF	 EFCH1501TCB3	 EFCH1575PDB1
 EFCH1575TCA2	 EFCH1575TDA1	 EFCH1575TDB1	 EFCH1747TDF1	 EFCH1765MTE3

Contact us: [Info@Y-IC.com](mailto:Info@Y-IC.com)

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